

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P45K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

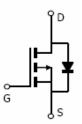
General Features

- V_{DS} =-60V, I_{D} =-45A $R_{DS(ON)}$ <35m Ω @ V_{GS} =-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P45K	NCE60P45K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	-45	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	-31.8	Α
Pulsed Drain Current	I _{DM}	180	Α
Maximum Power Dissipation	P _D	110	W
Derating factor		0.73	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	168	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{eJC}	1.36	°C/W



Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-2.0	-2.6	-3.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-20A	-	31	35	mΩ
Forward Transconductance	g FS	V_{DS} =-5 V , I_{D} =-20 A	-	20	_	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ - 20\/\/ -0\/	-	2049	_	PF
Output Capacitance	Coss	V_{DS} =-30V, V_{GS} =0V, F=1.0MHz	-	112.7	-	PF
Reverse Transfer Capacitance	C _{rss}	r-1.0Winz	-	88.7	_	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t _{d(on)}		-	13	_	nS
Turn-on Rise Time	t _r	V_{DD} =-30 V , I_{D} =-20 A	-	14	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{GEN} =3 Ω	-	39	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	\/ - 20\/ - 20 \	-	35.1	-	nC
Gate-Source Charge	Q_{gs}	V_{DS} =-30V, I_{D} =-20A, V_{GS} =-10V	-	9	-	nC
Gate-Drain Charge	Q_{gd}	VGS10V	-	7.9	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	-45	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = -20A	-	-	40	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	-	70	nC

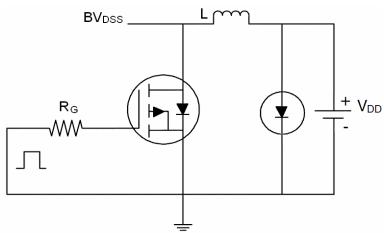
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- **4.** Guaranteed by design, not subject to production
- **5.** E_{AS} condition: Tj=25 $^{\circ}\text{C}$,V_{DD}=-30V,V_G=-10V,L=0.5mH,Rg=25 Ω

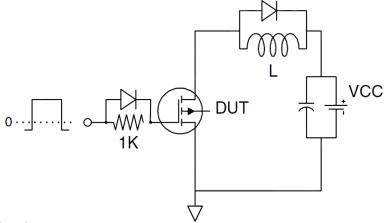


Test Circuit

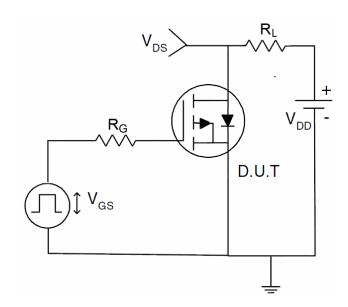
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit

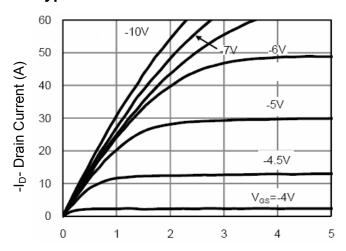


3) Switch Time Test Circuit



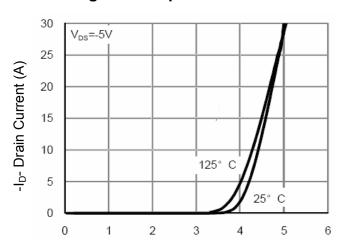


Typical Electrical and Thermal Characteristics (Curves)



-Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics



-Vgs Gate-Source Voltage (V)

Figure 2 Transfer Characteristics

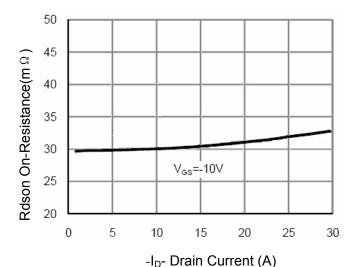


Figure 3 Rdson- Drain Current

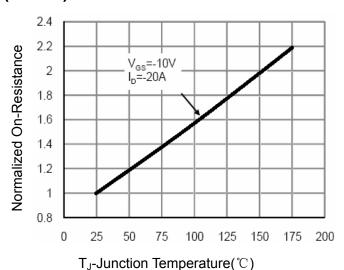


Figure 4 Rdson-JunctionTemperature

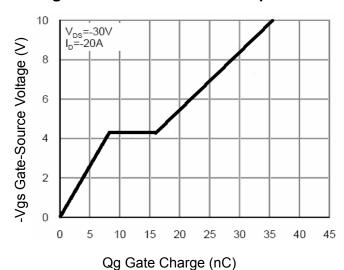
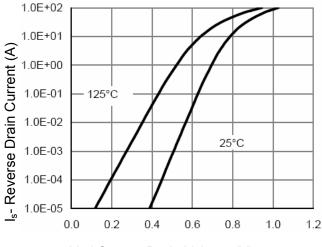


Figure 5 Gate Charge



-Vsd Source-Drain Voltage (V)

Figure 6 Source- Drain Diode Forward



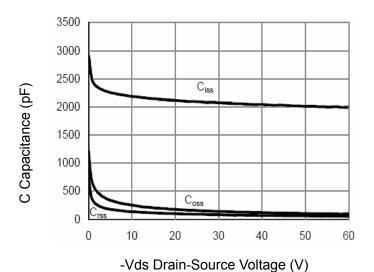
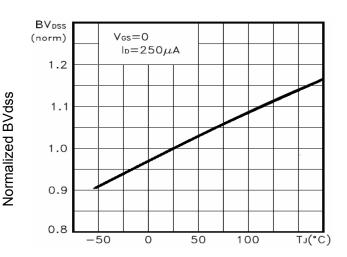
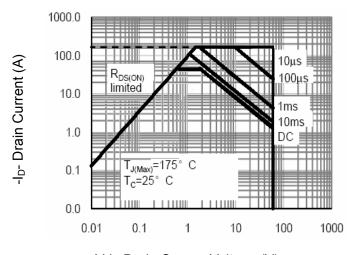


Figure 7 Capacitance vs Vds



 T_J -Junction Temperature (°C) Figure 9 BV_{DSS} vs Junction Temperature



-Vds Drain-Source Voltage (V)
Figure 8 Safe Operation Area

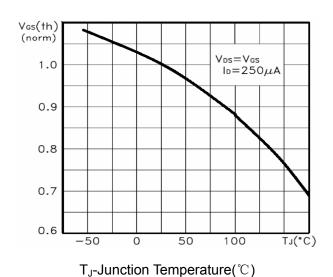
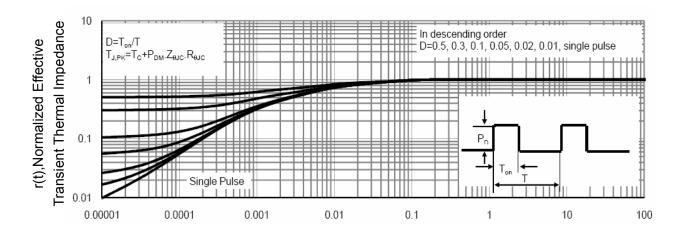


Figure 10 V_{GS(th)} vs Junction Temperature

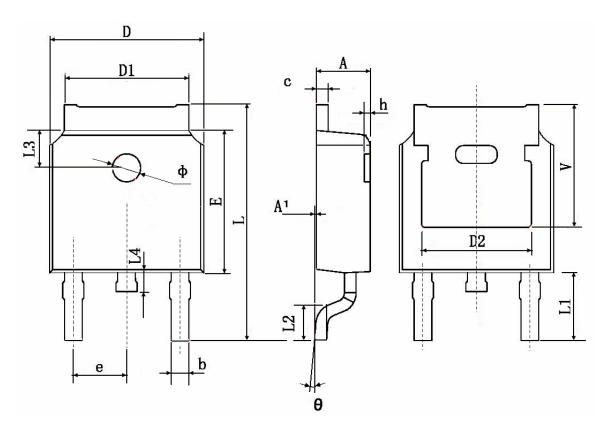


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



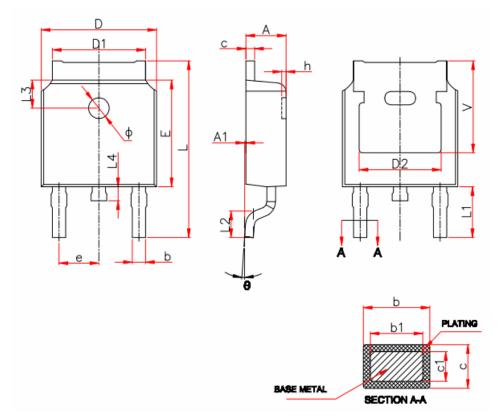
TO-252(C) Package Information



Comple of	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	D2 4.830 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.90	0 TYP.	0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.60	1.600 TYP.		TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	V 5.350 TYP.		0.211	TYP.	



TO-252(E) Package Information



Symbol	Millin	Millimeters		
Symbol	Min.	Max.		
Α	2.20	2.40		
A1	0.00	0.13		
b	0.66	0.86		
b1	0.73	0.79		
С	0.46	0.58		
c1	0.50	0.52		
D	6.50	6.70		
D1	5.10	5.46		
D2	4.83	REF.		
E	6.00	6.20		
е	2.19	2.39		
L	9.80	10.40		
L1	2.90	REF.		
L2	1.40	1.70		
L3	1.60 REF.			
L4	0.60	1.00		
Ф	1.10	1.30		
θ	0°	8°		



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